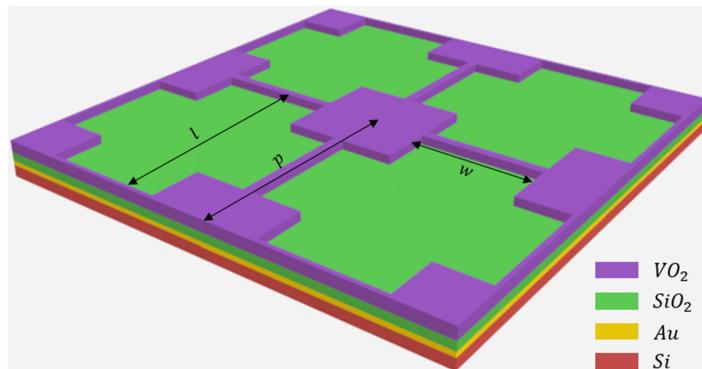


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# Terahertz Absorber With Reconfigurable Bandwidth Based on Isotropic Vanadium Dioxide Metasurfaces

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**Abstract:** The design of a broadband tunable absorber is proposed based on a thin vanadium dioxide metasurface, which is composed of a simple array of vanadium dioxide and a bottom gold film. When the conductivity of vanadium dioxide is equal to  $2000 \Omega^{-1}\text{cm}^{-1}$ , simulated absorptance exceeds 90% with 71% bandwidth from 0.47 to 0.99 THz and full width at half maximum is 98% from 0.354 to 1.036 THz with center frequency of 0.695 THz. Simulated results show that absorptance peak can be tuned from 5% to 100% when the conductivity changes continually from  $10 \Omega^{-1}\text{cm}^{-1}$  to  $2000 \Omega^{-1}\text{cm}^{-1}$ . The designed absorber may have useful applications in terahertz spectrum such as energy harvesting, thermal emitter, and sensing.

**Index Terms:** Absorber, metasurface, vanadium oxide.

## 1. Introduction

In the past several years, metamaterial absorber (MMA), one kind of electromagnetic absorber made of metamaterial (MM) resonators, has been attracting great attention and making huge progress [1]–[17]. Most of the proposed MMAs are composed of two metallic layers separated by dielectric material. Subwavelength micro- and nano-structures based on metal-insulator-metal (MIM) are often employed to get perfect absorption, and localized surface plasmon polaritons (LSPPs) exhibit an absorption independent on incident angle. Such absorbers are very promising for various applications, such as photodetector [2], [3], photovoltaic cell [4], [5], and stealth technology [6], [7]. However, absorption bandwidths of these MMAs are frequently narrow since LSPP resonance is limited in most cases to a single resonant mode. Absorption spectra can be widened by combining different structures with different widths, sizes, and shapes. In order to improve bandwidth, some efforts have been made from microwave [8], [9], terahertz [10], [11] to optical frequencies [12], [13], which often includes multiple resonators with different sizes [14], [15] or multilayer structure with different geometrical dimensions [16], [17]. T. Jang *et al.* designed an optically transparent, flexible, and polarization-insensitive broadband microwave absorber [9]. It is designed to have two

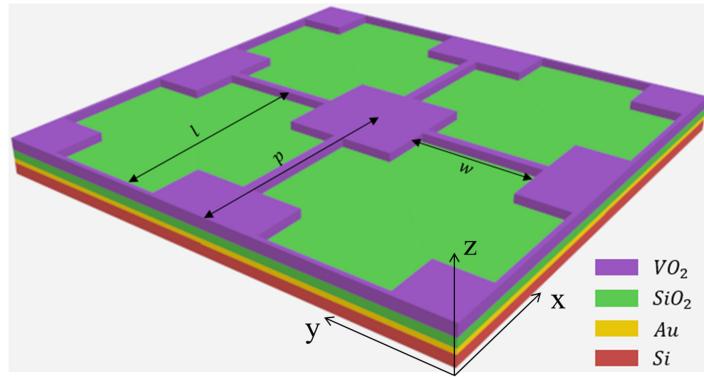


Fig. 1. Schematic of the designed broadband absorber, consisting of periodic air cross hole in  $VO_2$  film (purple), a silica spacer (green), and the gold film (yellow). The whole system is deposited on silicon (red) substrate.

overlapping resonances of the bow-tie array, which originates from the fundamental resonance mode and the coupling between the adjacent elements. Z. Song *et al.* studied a wideband absorber based on a silicon terahertz metasurface [11]. L. Lei *et al.* presented a design of an ultra-wideband absorber consisting of titanium-silica periodic cubes and an aluminum substrate [13]. H. Deng *et al.* demonstrated a broadband absorber with infrared wavelength ranging from  $1 \mu\text{m}$  to  $5 \mu\text{m}$ . It has two stacked chromium ring resonators on a reflective chromium mirror [17]. The configurations of these designs are not simple, and they require some complicated fabrication procedures. At the same time, the position and intensity of absorption peak are usually unchanged once the structure of MMA is fabricated [18]–[25].

In potential applications, tunable absorber is more attractive for the smart design. So dynamically tunable absorbers with the simple structure are desired. The transition behavior of vanadium oxide ( $VO_2$ ) between insulator and metal is well known around 340 K. With the increase of temperature, lattice structure of  $VO_2$  changes from monoclinic to tetragonal structure, and the corresponding electrical conductivity increases by several orders of magnitude during transformation process. It has wide potential in temperature sensitive photonic, electronic, and thermal devices. Combining MM with  $VO_2$  thin film or small particle is a promising way to dynamically regulate electromagnetic properties of some practical devices [26]–[31]. In 2010, W. Huang *et al.* presented a *gold strip/VO<sub>2</sub> spacer/gold strip* sandwich MM to study the optical response [26]. Their results show that nanostructures can be used as dynamic temperature-controlled optical switch. In 2012, M. A. Kats *et al.* showed perfect absorption in a single lossy  $VO_2$  layer [27]. The design generates 99.75% absorption at  $\lambda = 11.6 \mu\text{m}$ . In 2015, H. Kocer *et al.* demonstrated a thermally tunable short-wavelength infrared resonant absorber by heating up hybrid gold- $VO_2$  nanostructures [28]. In the terahertz frequency region, dielectric constant of  $VO_2$  changes several orders of magnitude when it experiences phase transition. Here we propose a composite  $VO_2$  metasurface with the sandwich microstructure to dynamically regulate absorption properties.

## 2. Methods

As shown in Fig. 1, the basic unit cell of the designed absorber consists of one air cross hole in  $VO_2$  and a background gold plane with thickness of  $0.2 \mu\text{m}$  which is much larger than the skin depth  $0.06 \mu\text{m}$  to prevent any transmission. The  $VO_2$  patches are separated by a  $SiO_2$  dielectric spacer from the background gold plane. After some carefully calculations based on cruise algorithm, the optimal geometrical parameters are obtained. The chosen width, length, and period of air crosses in simulation are  $w = 80 \mu\text{m}$ ,  $l = 172 \mu\text{m}$ , and  $p = 175 \mu\text{m}$ . The thicknesses of  $VO_2$  and  $SiO_2$  are  $0.08 \mu\text{m}$  and  $52 \mu\text{m}$ . A variable conductivity of  $VO_2$  is assumed to mimic phase transition effect. The optical permittivity of  $VO_2$  is described by Drude model  $\varepsilon(\omega) = \varepsilon_\infty - \frac{\omega_p^2(\sigma)}{\omega^2 + i\gamma\omega}$  in the terahertz range,

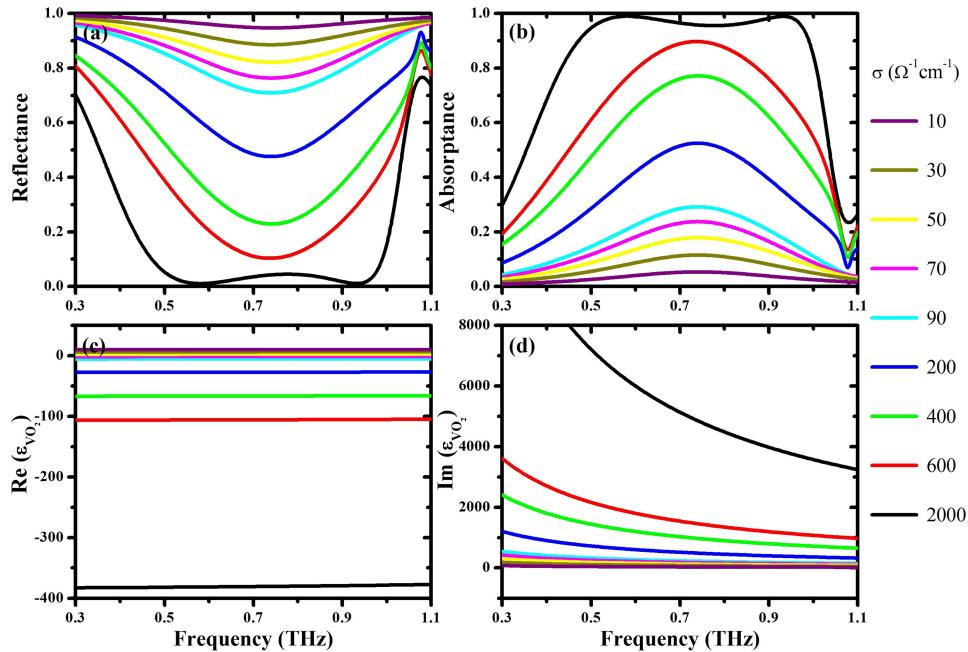


Fig. 2. Calculated reflectance (a) and absorptance (b) spectra with different conductivities of  $VO_2$  under normal incidence. Real (c) and imaginary (d) parts of  $VO_2$  permittivity.

where  $\varepsilon_\infty = 12$  is dielectric permittivity at high frequency,  $\omega_p(\sigma)$  is the plasma frequency dependent on conductivity and  $\gamma$  is the collision frequency [30], [31]. Besides,  $\omega_p^2(\sigma)$  and  $\sigma$  are proportional to free carrier density. The plasma frequency at  $\sigma$  can be approximately described by  $\omega_p^2(\sigma) = \frac{\sigma}{\sigma_0} \omega_p^2(\sigma_0)$  with  $\sigma_0 = 3 \times 10^3 \Omega^{-1}\text{cm}^{-1}$ ,  $\omega_p(\sigma_0) = 1.4 \times 10^{15} \text{ rad/s}$ , and  $\gamma = 5.75 \times 10^{13} \text{ rad/s}$  which is independent of  $\sigma$ . The permittivity of gold is also described by Drude model  $\varepsilon_{Au} = 1 - \omega_p^2/\omega(\omega + i\Gamma)$  with plasma frequency  $\omega_p = 1.37 \times 10^{16} \text{ rad/s}$  and collision frequency  $\Gamma = 1.2 \times 10^{14} \text{ rad/s}$  [32]. The dielectric constant of  $\text{SiO}_2$  is 3.8 with negligible loss at terahertz frequencies [33], [34].

### 3. Results

Due to the existence of the bottom  $0.2 \mu\text{m}$  gold film with the skin depth of  $0.06 \mu\text{m}$  to suppress wave transmission (transmittance ( $T$ ),  $T = 0$ ), absorptance ( $A$ ) can be calculated by  $A = 1 - R - T = 1 - |S_{11}|^2 - |S_{21}|^2$ , where  $R$  is the total reflectance. Absorptance can be maximized by minimization of reflectance from the top surface of the proposed structure. To verify our design, full wave electromagnetic simulation (finite element method-Comsol Multiphysics) is performed to get reflectance and then absorptance. Periodic boundary conditions are set in all  $xz$  and  $yz$  planes to assume an infinite array. Under normal incidence, simulated absorptance spectra of the proposed absorber are depicted in Fig. 2 with different conductivities. From these simulation results, we can find that when the conductivity of  $VO_2$  is equal to  $2000 \Omega^{-1}\text{cm}^{-1}$ , absorptance bandwidth of above 90% absorptance is from 0.47 THz to 0.99 THz, and the central position is at 0.73 THz. But when the conductivity of  $VO_2$  is equal to  $10 \Omega^{-1}\text{cm}^{-1}$ , working bandwidth becomes narrow and the biggest value is only 5%. To reveal the tuning mechanism of absorber, real and imaginary parts of  $VO_2$  permittivity as a function of frequency are plotted in Figs. 2(c)-(d). Real and imaginary parts of  $VO_2$  permittivity obviously change in the terahertz range when the conductivity of  $VO_2$  varies from  $10 \Omega^{-1}\text{cm}^{-1}$  to  $2000 \Omega^{-1}\text{cm}^{-1}$ . Furthermore, we can see the change of imaginary part under different conductivities is much larger than that of real part. Thus, the central positions of peak keep almost unchanged, but spectral intensity change is very remarkable due to the shift of imaginary part of  $VO_2$  permittivity. So  $VO_2$  can be used for absorption tuning in terahertz spectrum. It can

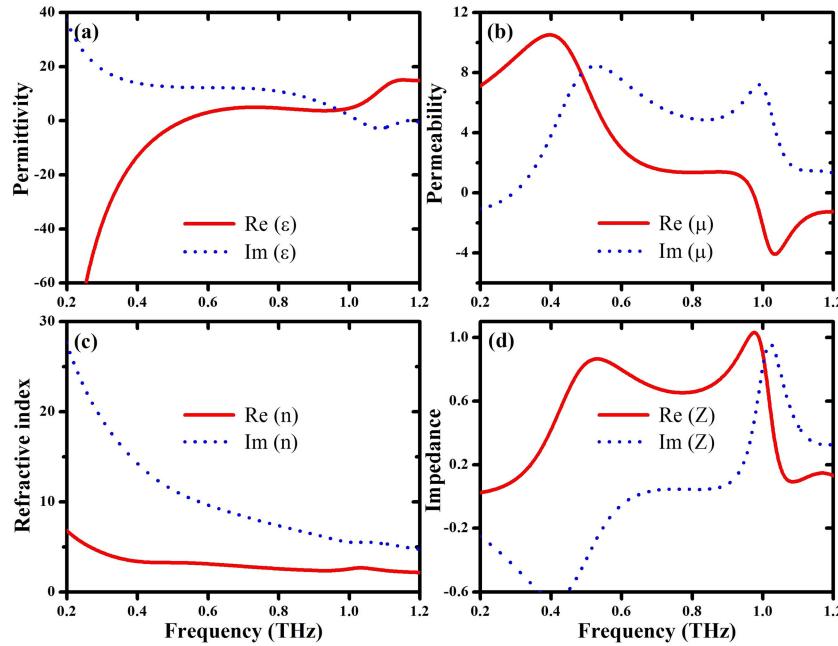


Fig. 3. Retrieved effective physical parameters (a) permittivity, (b) permeability, (c) refractive index, and (d) impedance in the case of perfect absorption when  $\sigma = 2000 \Omega^{-1} \text{cm}^{-1}$ .

serve as a tunable material by controlling conductivity, and then working bandwidth and efficiency are dynamically realized.

In order to obtain perfect absorption, impedance of absorber should be matched to that of vacuum. Because the ratio of center wavelength  $410.96 \mu\text{m}$  (0.73 THz) to period  $175 \mu\text{m}$  is  $\sim 2.35$  under normal incidence, impedance of the designed system can be obtained from the combination of the impedances of air cross hole in  $\text{VO}_2$  and a dielectric layer with the ground gold plane. The calculated effective permittivity in Fig. 3(a) is a Drude model, and there is no obvious character. In Fig. 3(b), there are two resonances in permeability, which results in two impedance-matching points. The impedance is normalized to the value  $377 \Omega$  of vacuum in Fig. 3(d), and its unit is  $\Omega$ .

The effective impedance of the designed system can be retrieved from  $Z = \sqrt{\frac{\mu}{\epsilon}} = \sqrt{\frac{(1+S_{11})^2-S_{21}^2}{(1-S_{11})^2-S_{21}^2}}$ , the corresponding real and imaginary parts of the effective impedance are calculated from the inversion of S-parameters method and plotted in Fig. 3(d). Real part of effective impedance of the designed system is almost matched to that of free space, and imaginary part of effective refractive index is very large. As a result, there are two matched bands where reflected wave is minimized.

#### 4. Discussions

Next, the influences of geometrical parameters on absorptance are investigated. We consider the situation where the conductivity of  $\text{VO}_2$  is equal to  $2000 \Omega^{-1} \text{cm}^{-1}$ , and the thicknesses of  $\text{VO}_2$  and  $\text{SiO}_2$  are varied. Fig. 4(a) shows calculated absorptance as a function of frequency and thickness of  $\text{VO}_2$  with other parameters unchanged under normal incidence. From Fig. 4(a), we can see that absorptance is sensitive to the thickness of  $\text{VO}_2$ . It results from the fact that imaginary part of  $\text{VO}_2$  plays an important role in absorption. When the thickness of  $\text{VO}_2$  is very thin, the coupling between  $\text{VO}_2$  and metallic substrate is very weak, and the corresponding impedance is not matched to that of vacuum. When the thickness of  $\text{VO}_2$  is enough thick, it will strongly reflect electromagnetic wave. Fig. 4(b) shows calculated absorptance as a function of frequency and thickness of  $\text{SiO}_2$  with other parameters unchanged under normal incidence. From Fig. 4(b), we can find that when

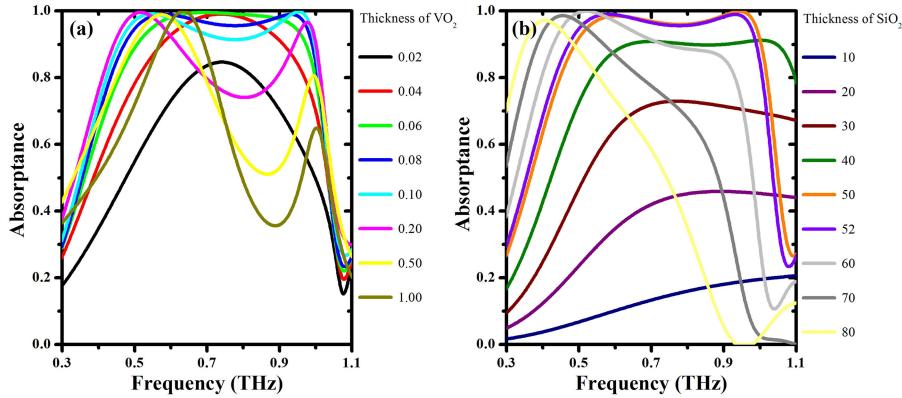


Fig. 4. Calculated absorptance as a function of frequency and thickness of  $\text{VO}_2$  (a) and  $\text{SiO}_2$  (b) when  $\sigma = 2000 \Omega^{-1}\text{cm}^{-1}$ .

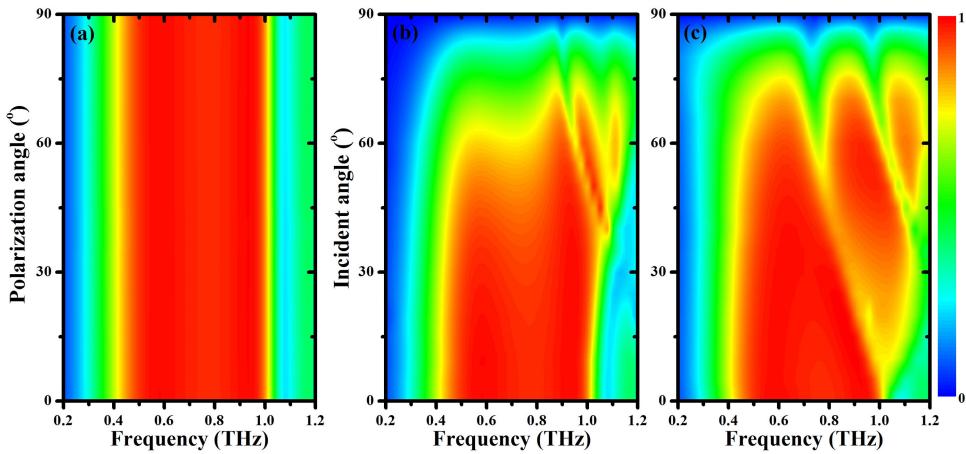


Fig. 5. Calculated absorptance dependence on polarization angle (a) and incidence angle of TE (b) and TM (c) polarizations when  $\sigma = 2000 \Omega^{-1}\text{cm}^{-1}$ .

the thickness of  $\text{SiO}_2$  is increased, resonance peak will have an obvious red-shift.  $\text{SiO}_2$  plays the role of cavity, and different thickness of  $\text{SiO}_2$  will have different field distributions, and has different effective impedance. When the thickness of  $\text{SiO}_2$  is small, the interaction between metallic structure and  $\text{VO}_2$  is very strong. A little change in the thickness of  $\text{SiO}_2$  will have an obvious influence on the absorptance spectrum. When the thickness of  $\text{SiO}_2$  is enough large, the interaction between metallic structure and  $\text{VO}_2$  becomes weak. The thickness of  $\text{SiO}_2$  has a great influence on bandwidth and intensity of absorptance and have an optimized value for achieving maximal broadband absorption. It is mainly caused by the fact that impedance-matching condition is strongly dependent on the thickness of  $\text{SiO}_2$ .

In practical application, polarization insensitivity is an important property for absorber. So it is necessary to consider polarization dependence of the proposed design. Polarization angle is defined between electric field vector and  $x$  axis in the  $xy$  plane. Absorptance characteristics under normally incident electromagnetic wave are plotted in Fig. 5(a) with different polarization directions. It can be observed that absorptance spectrum is insensitive to polarization angle, which is attributed to the symmetric property of the designed structure. At the same time, incident angle between wave vector and  $z$  axis is defined. The influence of incident angle on absorptance characteristics is also investigated. Fig. 5(b) presents absorptance spectra of transverse electric (TE) polarization as a function of frequency and incident angle. It can be seen that absorptance bandwidth remains almost unchanged when incident angle is smaller than  $45^\circ$ . When incident angle continues to increase,

absorptance intensity becomes weaker and then disappears. Fig. 5(c) presents absorptance spectra of transverse magnetic (TM) polarization as a function of frequency and incident angle. When incident angle is larger than  $15^\circ$ , the first absorptance bandwidth becomes narrower and some higher-order modes appear. The ratio of wavelength  $300 \mu\text{m}$  (1.0 THz) to period  $175 \mu\text{m}$  is  $\sim 1.71$ , which is not enough subwavelength for oblique incidence especially at large angle.

## 5. Conclusion

To summarize, a broadband terahertz absorber has been designed and numerically verified based on a simple  $\text{VO}_2$  metasurface. The proposed system shows 71% absorption bandwidth of above 90% absorptance. The proposed absorber has a thin thickness and the ratio of center wavelength  $410.96 \mu\text{m}$  (0.73 THz) to thickness  $52.28 \mu\text{m}$  is  $\sim 7.86$ . Because of periodically simple symmetric patterned structures, absorber is robust against polarization of incident wave. The absorptance average level remains very well for TE-polarized wave with an incident angle up to  $45^\circ$ . The performance of absorption behavior for TM-polarized wave becomes a little worse at incident angle larger than  $30^\circ$  due to higher order scattering. The structure presents the advantages of simple configuration, high absorptance, and broad bandwidth. These properties make it a good candidate for the useful design in photovoltaics, thermal emitter, and stealth technology.

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